Am27S33/27S33A
4,096-Bit (1024x4) Bipolar PROM

DISTINCTIVE CHARACTERISTICS

- High speed
- Highly reliable, ultra-fast programming Platinum-Silicide fuses
- High programming yield

- Low-current PNP inputs
- High-current open-collector and three-state outputs
- Fast chip select

GENERAL DESCRIPTION

The Am27S33 (1024 words by 4 bits) is a Schottky TTL Programmable Read-Only Memory (PROM).

This device is available in three-state (Am27S33) output versions. These outputs are compatible with low-power Schotkky bus standards capable of satisfying the require-

ments of a variety of microprogrammable controls, mapping functions, code conversion, or logic replacement. Easy word-depth expansion is facilitated by active LOW ($\overline{G_1}$ & $\overline{G_2}$) output enables.
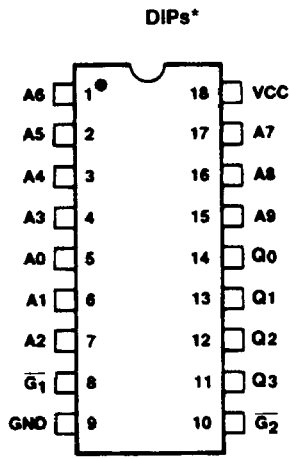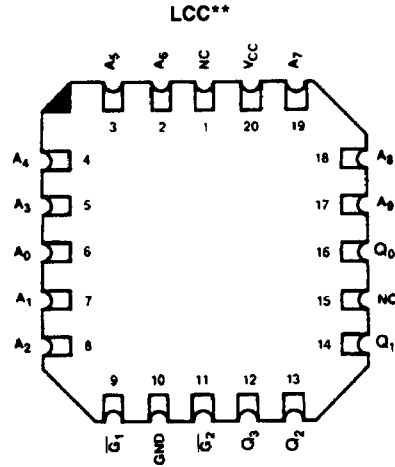
BLOCK DIAGRAM

BD006190
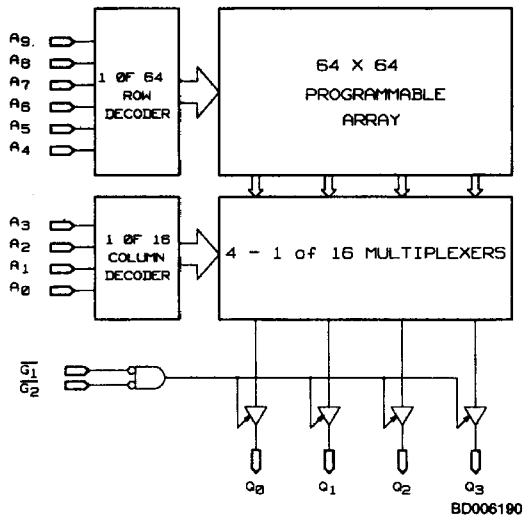
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PRODUCT SELECTOR GUIDE

Three-State Part Number	Am27S33A		Am27S33	
Address Access Time	35 ns	45 ns	55 ns	70 ns
Operating Range	C	M	C	M

CONNECTION DIAGRAMS
Top View

DIPs*

```
        ┌────┐∪┌────┐
  A6 ──┤ 1●      18 ├── VCC
  A5 ──┤ 2       17 ├── A7
  A4 ──┤ 3       16 ├── A8
  A3 ──┤ 4       15 ├── A9
  A0 ──┤ 5       14 ├── Q0
  A1 ──┤ 6       13 ├── Q1
  A2 ──┤ 7       12 ├── Q2
  G̅₁ ──┤ 8       11 ├── Q3
 GND ──┤ 9       10 ├── G̅₂
        └─────────────┘
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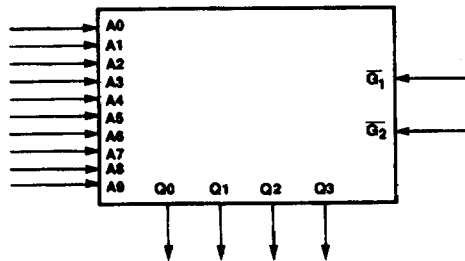CD000721

LCC**

CD000731

*Also available in 18-pin Flatpack. Pinout identical to DIPs.
**Also available in a 20-pin square PLCC. Pinout identical to LCC.

Note: Pin 1 is marked for orientation.
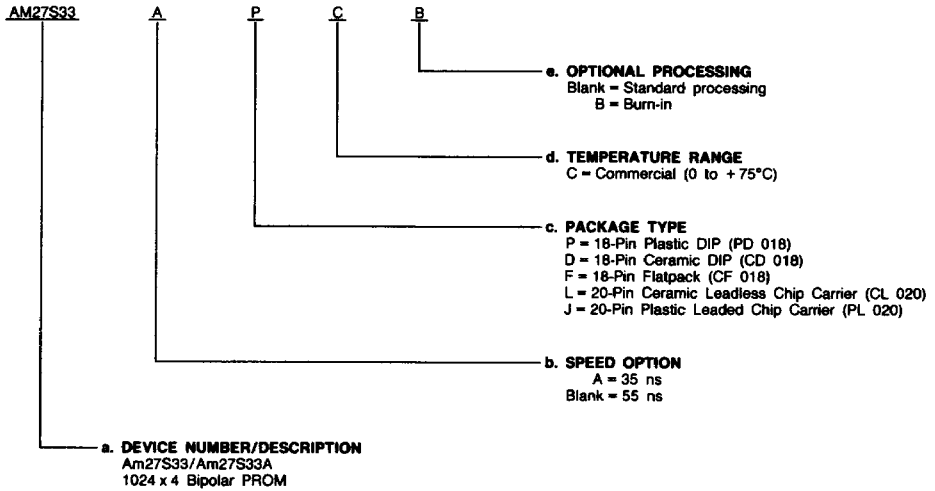
LOGIC SYMBOL

LS002500

ORDERING INFORMATION

Standard Products

AMD standard products are available in several packages and operating ranges. The order number (Valid Combination) is formed by a combination of: **a. Device Number**

        b. Speed Option (if applicable)

        c. Package Type

        d. Temperature Range

        e. Optional Processing

```
AM27S33        A      P      C      B
```

e. OPTIONAL PROCESSING
Blank = Standard processing
B = Burn-in

d. TEMPERATURE RANGE
C = Commercial (0 to +75°C)

c. PACKAGE TYPE
P = 18-Pin Plastic DIP (PD 018)
D = 18-Pin Ceramic DIP (CD 018)
F = 18-Pin Flatpack (CF 018)
L = 20-Pin Ceramic Leadless Chip Carrier (CL 020)
J = 20-Pin Plastic Leaded Chip Carrier (PL 020)

b. SPEED OPTION
A = 35 ns
Blank = 55 ns

a. DEVICE NUMBER/DESCRIPTION
Am27S33/Am27S33A
1024 x 4 Bipolar PROM

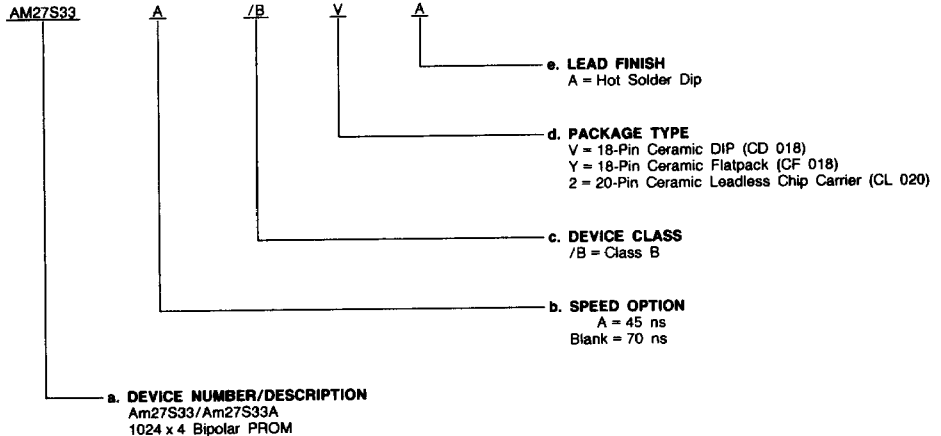| Valid Combinations	
AM27S33	PC, PCB, DC, DCB, FC, FCB, LC, LCB, JC,
AM27S33A	JCB

Valid Combinations

Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, to check on newly released combinations, and to obtain additional data on AMD's standard military grade products.

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MILITARY ORDERING INFORMATION

APL Products

AMD products for Aerospace and Defense applications are available in several packages and operating ranges. APL (Approved Products List) products are fully compliant with MIL-STD-883C requirements. The order number (Valid Combination) for APL products is formed by a combination of:
a. **Device Number**
b. **Speed Option** (if applicable)
c. **Device Class**
d. **Package Type**
e. **Lead Finish**

AM27S33   A   /B   V   A

e. LEAD FINISH
A = Hot Solder Dip

d. PACKAGE TYPE
V = 18-Pin Ceramic DIP (CD 018)
Y = 18-Pin Ceramic Flatpack (CF 018)
2 = 20-Pin Ceramic Leadless Chip Carrier (CL 020)

c. DEVICE CLASS
/B = Class B

b. SPEED OPTION
A = 45 ns
Blank = 70 ns

a. DEVICE NUMBER/DESCRIPTION
Am27S33/Am27S33A
1024 x 4 Bipolar PROM

Valid Combinations	
AM27S33	/BVA, /BYA,
AM27S33A	/B2A

Valid Combinations

Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations or to check for newly released valid combinations.

Group A Tests

Group A tests consist of Subgroups
1, 2, 3, 7, 8, 9, 10, 11.

MILITARY BURN-IN

Military burn-in is in accordance with the current revision of MIL-STD-883, Test Method 1015, Conditions A through E. Test conditions are selected at AMD's option.

PIN DESCRIPTION

$A_0 - A_9$ **Address Inputs**
The 10-bit field presented at the address inputs selects one of 1024 memory locations to be read from.

$Q_0 - Q_3$ **Data Output Port**
The outputs whose state represents the data read from the selected memory locations.

$\overline{G_1}, \overline{G_2}$ **Output Enable**
Provides direct control of the Q-output buffers. Outputs disabled forces all open-collector outputs to an OFF state and all three-state outputs to a floating or high-impedance state.

Enable = $\overline{G_1} \cdot \overline{G_2}$
Disable = $\overline{\overline{G_1} \cdot \overline{G_2}}$
= $G_1 + G_2$

V_{CC} **Device Power Supply Pin**
The most positive of the logic power supply pins.

GND **Device Power Supply Pin**
The most negative of the logic power supply pins.

Am27S33/27S33A

ABSOLUTE MAXIMUM RATINGS

Storage Temperature .... −65 to +150°C
Ambient Temperature with
    Power Applied .... −55 to +125°C
Supply Voltage .... −0.5 V to +7.0 V
DC Voltage Applied to Outputs
    (Except During Programming) .... −0.5 V to +V_{CC} Max.
DC Voltage Applied to Outputs
    During Programming .... 21 V
Output Current into Outputs During
    Programming (Max Duration of 1 sec) .... 250 mA
DC Input Voltage .... −0.5 V to +5.5 V
DC Input Current .... −30 mA to +5 mA

Stresses above those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to absolute maximum ratings for extended periods may affect device reliability.

OPERATING RANGES

Commercial (C) Devices
    Ambient Temperature (T_A) .... 0 to +75°C
    Supply Voltage (V_{CC}) .... +475 V to +5.25 V

Military (M) Devices*
    Case Temperature (T_C) .... −55 to +125°C
    Supply Voltage (V_{CC}) .... +4.5 V to +5.5 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

*Military Product 100% tested at T_C = +25°C, +125°C, and −55°C.

DC CHARACTERISTICS over operating ranges unless otherwise specified (for APL Products, Group A, Subgroups 1, 2, 3 are tested unless otherwise noted)

Parameter Symbol	Parameter Description	Test Conditions		Min.	Typ.	Max.	Unit
V_{OH}	Output HIGH Voltage	V_{CC} = Min., I_{OH} = −2.0 mA V_{IN} = V_{IH} or V_{IL}		2.4			V
V_{OL}	Output LOW Voltage	V_{CC} = Min., I_{OL} = 16 mA V_{IN} = V_{IH} or V_{IL}				0.45	V
V_{IH}	Input HIGH Level	Guaranteed input logical HIGH voltage for all inputs (Note 1)		2.0			V
V_{IL}	Input LOW Level	Guaranteed input logical LOW voltage for all inputs (Note 1)				0.8	V
I_{IL}	Input LOW Current	V_{CC} = Max., V_{IN} = 0.45 V				−0.250	mA
I_{IH}	Input HIGH Current	V_{CC} = Max., V_{IN} = 2.7 V				25	μA
I_{SC} (Note 1)	Output Short-Circuit Current	V_{CC} = Max., V_{OUT} = 0.0 V (Note 2)		−20		−90	mA
I_{CC}	Power Supply Current	All inputs = GND, V_{CC} = Max.	COM'L			140	mA
			MIL			145	
V_I	Input Clamp Voltage	V_{CC} = Min., I_{IN} = −18 mA				−1.2	V
I_{CEX}	Output Leakage Current	V_{CC} = Max., $V_{\overline{G1}}$ = 2.4 V (Note 1)	$V_O = V_{CC}$			40	μA
			V_O = 2.4 V			40	
			V_O = 0.4 V			−40	
C_{IN}	Input Capacitance	V_{IN} = 2.0 V @ f = 1 MHz (Note 3) V_{CC} = 5 V, T_A = 25°C				5	pF
C_{OUT}	Output Capacitance	V_{OUT} = 2.0 V @ f = 1 MHz (Note 3) V_{CC} = 5 V, T_A = 25°C				8	

Notes: 1. V_{IL} and V_{IH} are input conditions of output tests and are not themselves directly tested. V_{IL} and V_{IH} are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.
2. Not more than one output should be shorted at a time. Duration of the short circuit should not be more than one second.
3. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.

SWITCHING CHARACTERISTICS over operating ranges unless otherwise specified (for APL Products, Group A, Subgroups 9, 10, 11 are tested unless otherwise noted*)

No.	Parameter Symbol	Parameter Description	Am27S33A COM'L Min.	Am27S33A COM'L Max.	Am27S33A MIL Min.	Am27S33A MIL Max.	Am27S33 COM'L Min.	Am27S33 COM'L Max.	Am27S33 MIL Min.	Am27S33 MIL Max.	Unit
1	TAVQV	Address Valid to Output Valid Access Time		35		45		55		70	ns
2	TGVQZ	Delay from Output Enable Valid to Output Hi-Z		20		25		25		30	ns
3	TGVQV	Delay from Output Enable Valid to Output Valid		20		25		25		30	ns

See also Switching Test Circuit.

Notes: 1. Tests are performed with input transition time of 5 ns or less, timing reference levels of 1.5 V, and input pulse levels of 0 to 3.0 V.
*Subgroups 7 and 8 apply to functional tests.

SWITCHING TEST CIRCUIT

TC000171
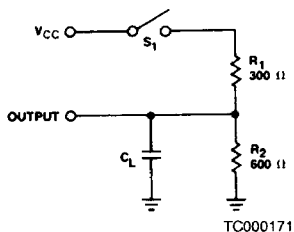
Notes: 1. TAVQV is tested with switch S_1 closed and $C_L = 50$ pF.
2. For three-state outputs, TGVQV is tested with $C_L = 50$ pF to the 1.5 V level; S_1 is open for high impedance to HIGH tests and closed for high impedance to LOW tests. TGVQZ is tested with $C_L = 5$ pF. HIGH to high-impedance tests are made with S_1 open to an output voltage of steady state HIGH -0.5 V; LOW to high-impedance tests are made with S_1 closed to the steady state LOW $+0.5$ V level.

SWITCHING WAVEFORMS

KEY TO SWITCHING WAVEFORM

WAVEFORM	INPUTS	OUTPUTS
	MUST BE STEADY	WILL BE STEADY
	MAY CHANGE FROM H TO L	WILL BE CHANGING FROM H TO L
	MAY CHANGE FROM L TO H	WILL BE CHANGING FROM L TO H
	DON'T CARE, ANY CHANGE PERMITTED	CHANGING, STATE UNKNOWN
	DOES NOT APPLY	CENTER LINE IS HIGH IMPEDANCE "OFF" STATE

KS000010

WF021250